

Features

- Seven Darlington pairs per package
- Output current 500 mA per driver (600 mA peak)
- Output voltage 50 V
- Integrated suppression diodes for inductive loads
- Outputs can be paralleled for higher current
- TTL/CMOS/PMOS/DTL compatible inputs
- Input pins placed opposite to output pins to simplify layout

Description

The ULN2001, ULN2002, ULN2003 and ULN2004 are high-voltage, high-current Darlington arrays each containing seven open collector Darlington pairs with common emitters. Each channel is rated at 500 mA and can withstand peak currents of 600 mA. Suppression diodes are included for inductive load driving and the inputs are pinned opposite the outputs to simplify board layout.

The versions interface to all common logic families: ULN2001 (general purpose, DTL, TTL, PMOS, CMOS); ULN2002 (14 - 25 V PMOS); ULN2003 (5 V TTL, CMOS); ULN2004 (6 - 15 V CMOS, PMOS).

These versatile devices are useful for driving a wide range of loads including solenoids, relay DC motors, LED display filament lamps, thermal printheads and high-power buffers.

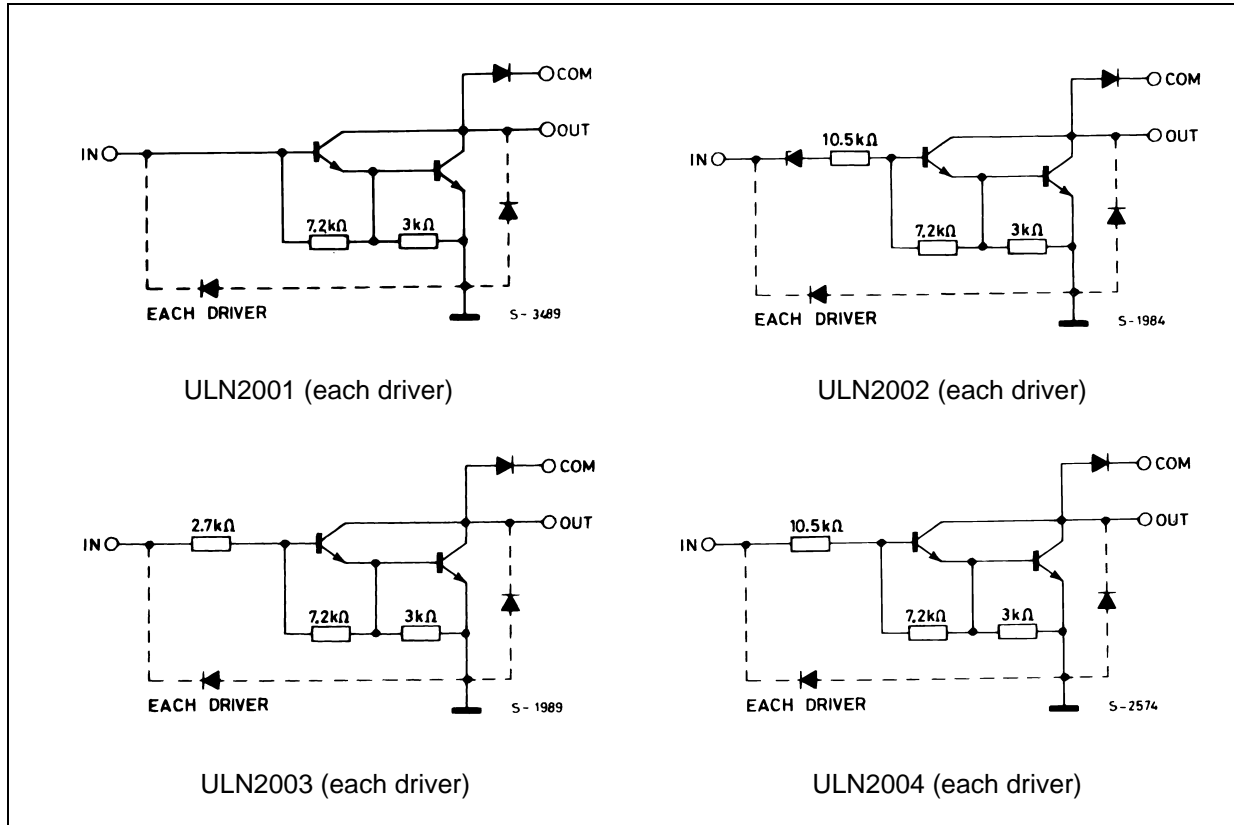
The ULN2001A/2002A/2003A and 2004A are supplied in a 16-pin DIP package with a copper leadframe to reduce thermal resistance. They are available also in small outline package (SO-16) as ULN2001D1/2002D1/2003D1/ 2004D1.

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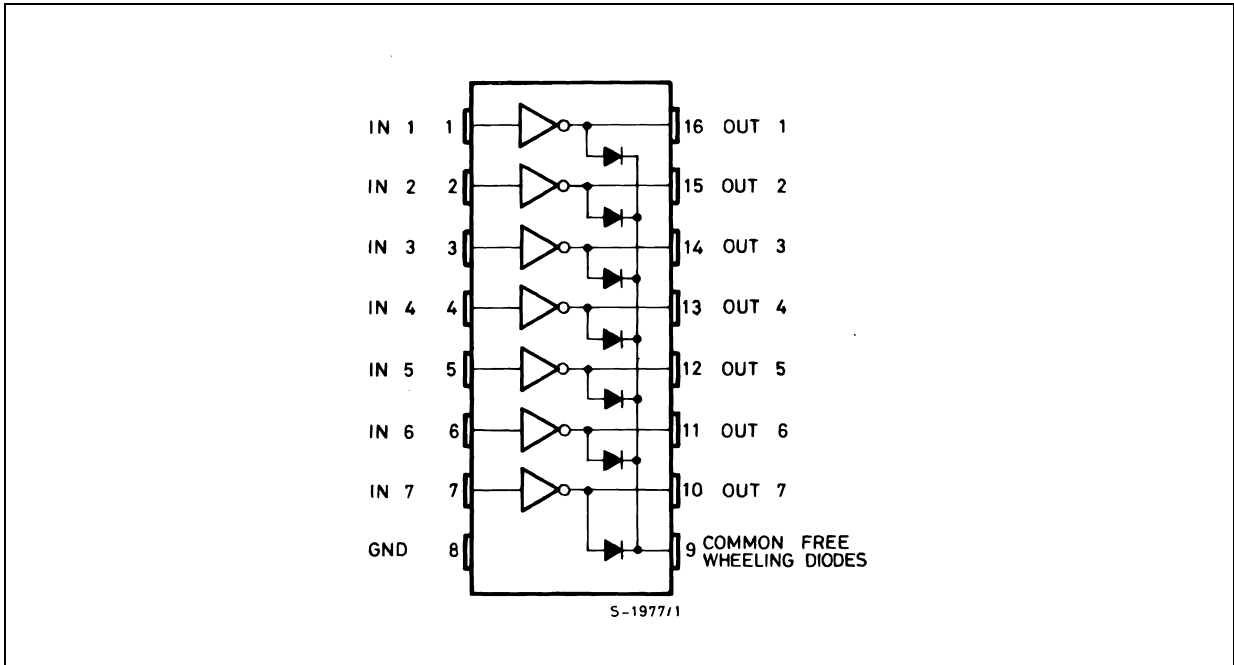
1 Diagram

Figure 1. Schematic diagram



2 Pin configuration

Figure 2. Pin connections (top view)



3 Maximum ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_O	Output voltage	50	V
V_I	Input voltage (for ULN2002A/D - 2003A/D - 2004A/D)	30	V
I_C	Continuous collector current	500	mA
I_B	Continuous base current	25	mA
I_F	Clamping diode continuous current	350	mA
V_R	Clamping diode reverse voltage	50	V
T_A	Operating ambient temperature range	- 40 to 85	°C
T_{STG}	Storage temperature range	- 55 to 150	°C
T_J	Junction temperature	150	°C
ESD	Electrostatic discharge rating - HBM	2	kV

Table 2. Thermal data

Symbol	Parameter	DIP-16	SO-16	Unit
R_{thJA}	Thermal resistance junction-ambient, Max.	70	120	°C/W

Note: Maximum power dissipation is a function of $T_{J(max)}$, R_{thJA} and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_{J(max)} - T_A) / R_{thJA}$. Operating at the absolute maximum T_J of +150°C can affect reliability.

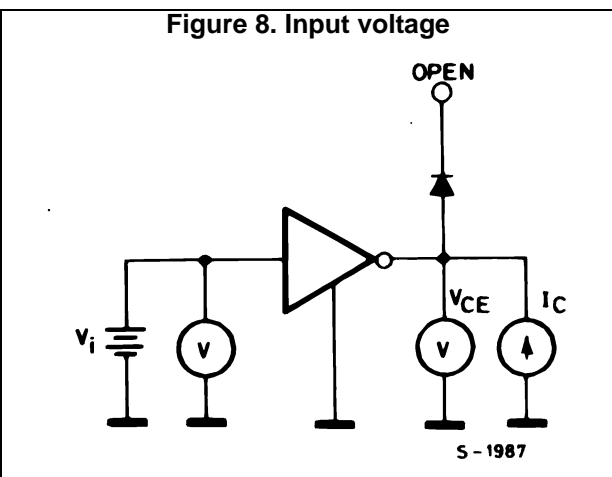
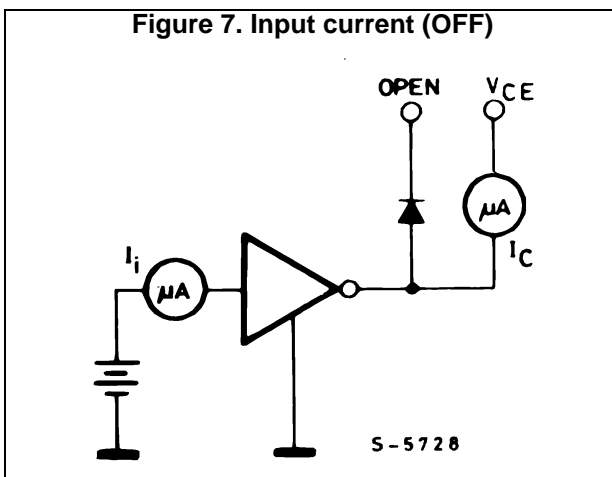
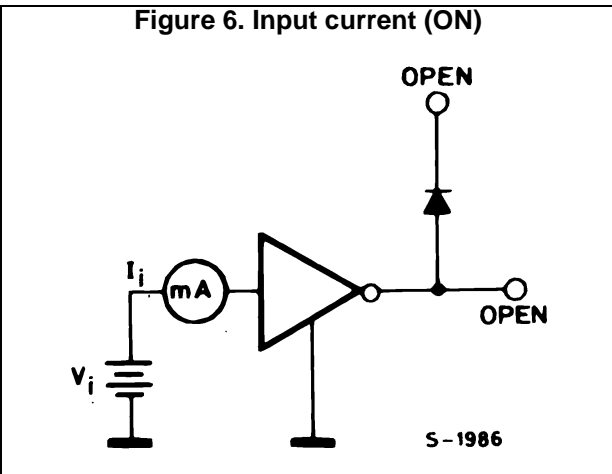
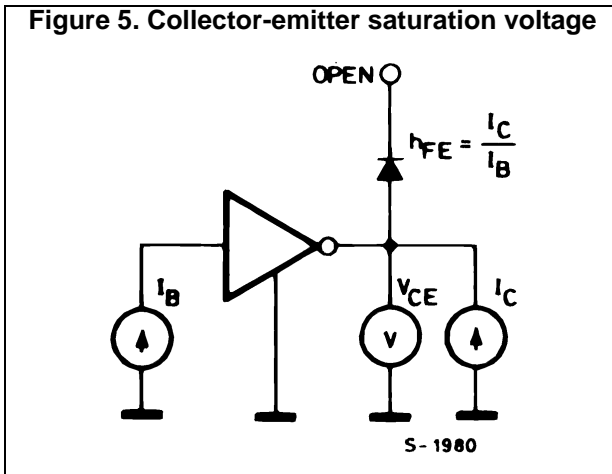
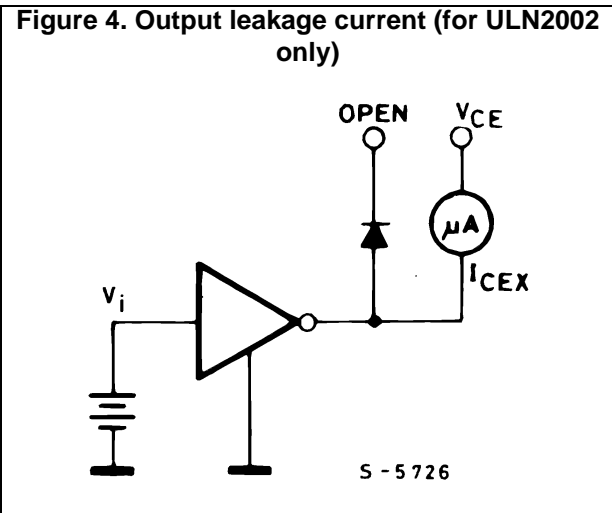
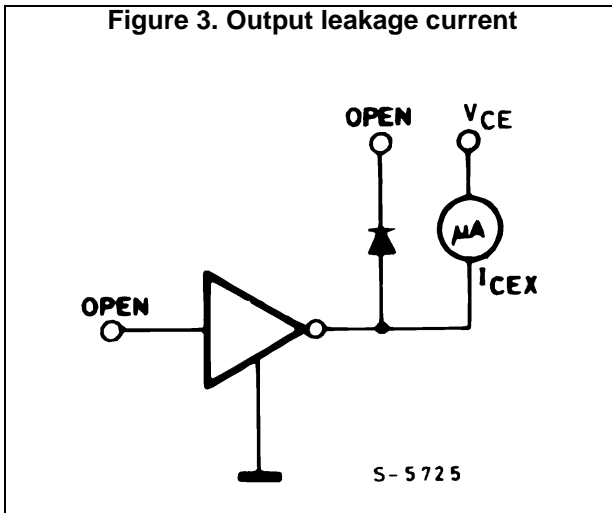
4 Electrical characteristics

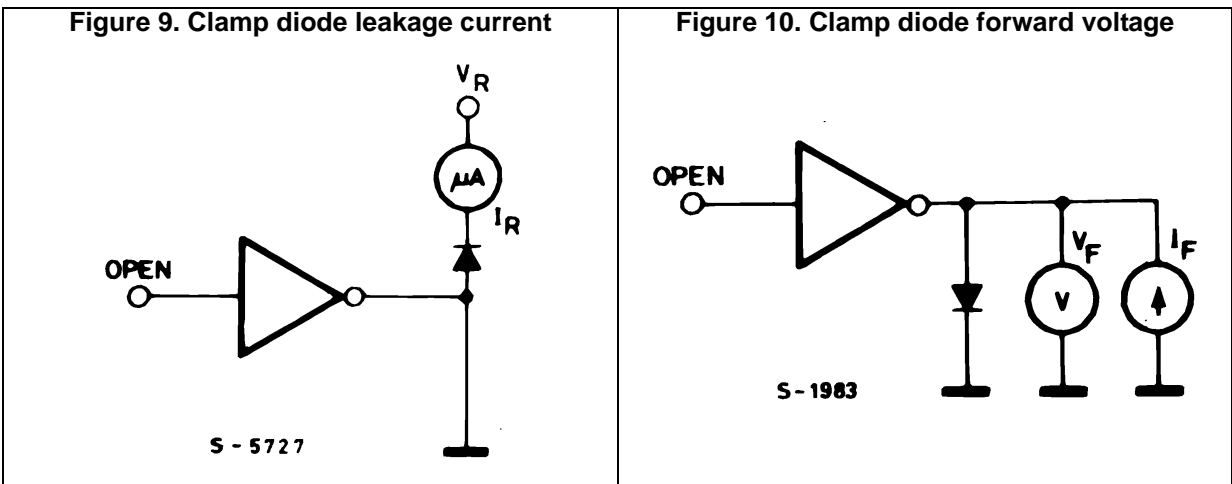
$T_A = 25\text{ °C}$ unless otherwise specified.

Table 3. Electrical characteristics

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
I_{CEX}	Output leakage current	$V_{CE} = 50\text{ V}$, (Figure 3)			50	μA
		$T_A = 85\text{ °C}$, $V_{CE} = 50\text{ V}$ (Figure 3)			100	
		$T_A = 85\text{ °C}$ for ULN2002, $V_{CE} = 50\text{ V}$, $V_I = 6\text{ V}$ (Figure 4)			500	
		$T_A = 85\text{ °C}$ for ULN2002, $V_{CE} = 50\text{ V}$, $V_I = 1\text{ V}$ (Figure 4)			500	
$V_{CE(SAT)}$	Collector-emitter saturation voltage (Figure 5)	$I_C = 100\text{ mA}$, $I_B = 250\text{ }\mu\text{A}$		0.9	1.1	V
		$I_C = 200\text{ mA}$, $I_B = 350\text{ }\mu\text{A}$		1.1	1.3	
		$I_C = 350\text{ mA}$, $I_B = 500\text{ }\mu\text{A}$		1.3	1.6	
$I_{I(ON)}$	Input current (Figure 6)	for ULN2002, $V_I = 17\text{ V}$		0.82	1.25	mA
		for ULN2003, $V_I = 3.85\text{ V}$		0.93	1.35	
		for ULN2004, $V_I = 5\text{ V}$ $V_I = 12\text{ V}$		0.35 1	0.5 1.45	
$I_{I(OFF)}$	Input current (Figure 7)	$T_A = 85\text{ °C}$, $I_C = 500\text{ }\mu\text{A}$	50	65		μA
$V_{I(ON)}$	Input voltage (Figure 8)	$V_{CE} = 2\text{ V}$, for ULN2002 $I_C = 300\text{ mA}$			13	V
		for ULN2003 $I_C = 200\text{ mA}$			2.4	
		$I_C = 250\text{ mA}$			2.7	
		$I_C = 300\text{ mA}$			3	
		for ULN2004 $I_C = 125\text{ mA}$			5	
		$I_C = 200\text{ mA}$			6	
		$I_C = 275\text{ mA}$ $I_C = 350\text{ mA}$			7 8	
h_{FE}	DC Forward current gain (Figure 5)	for ULN2001, $V_{CE} = 2\text{ V}$, $I_C = 350\text{ mA}$	1000			
C_I	Input capacitance			15	25	pF
t_{PLH}	Turn-on delay time	$0.5 V_I$ to $0.5 V_O$		0.25	1	μs
t_{PHL}	Turn-off delay time	$0.5 V_I$ to $0.5 V_O$		0.25	1	μs
I_R	Clamp diode leakage current (Figure 9)	$V_R = 50\text{ V}$			50	μA
		$T_A = 85\text{ °C}$, $V_R = 50\text{ V}$			100	
V_F	Clamp diode forward voltage (Figure 10)	$I_F = 350\text{ mA}$		1.7	2	V

5 Test circuits





6 Typical performance characteristics

Figure 11. Collector current vs. saturation voltage ($T_J = 25^\circ\text{C}$)

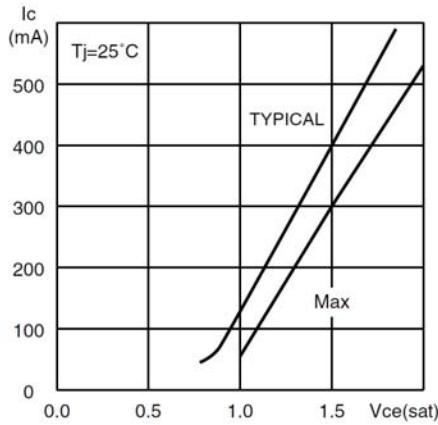


Figure 12. Collector current vs. saturation voltage

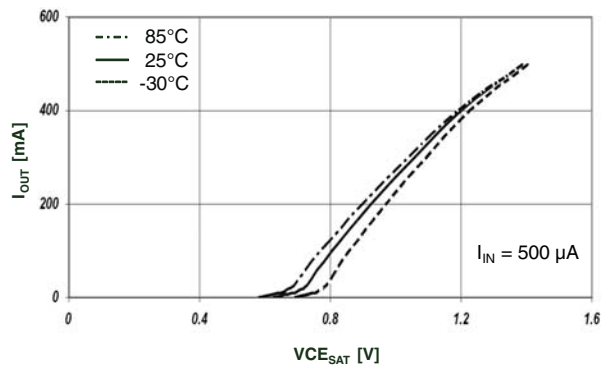


Figure 13. Input current vs. input voltage

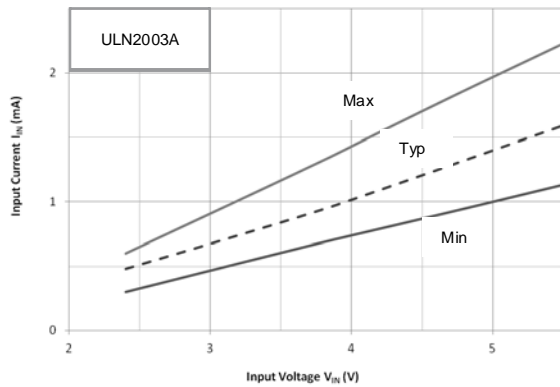


Figure 14. Input current vs. input voltage ($T_a = 25^\circ\text{C}$)

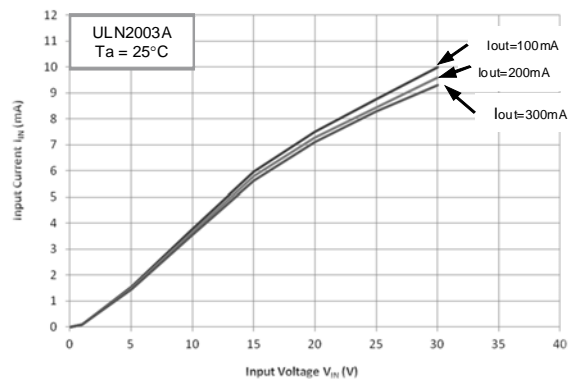


Figure 15. Collector current vs. input current

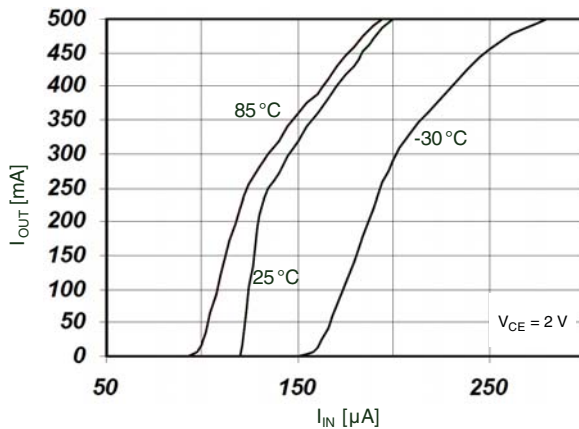


Figure 16. h_{FE} vs. output current

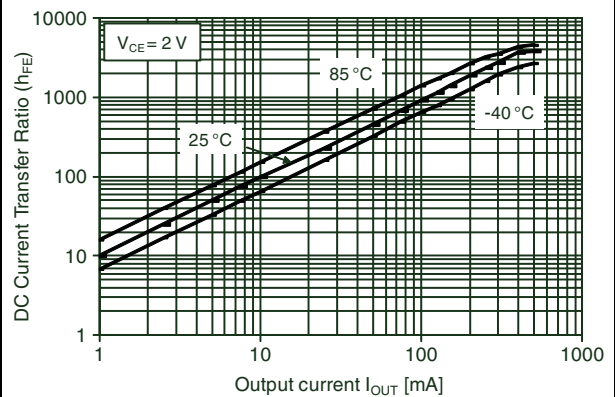


Figure 17. Peak collector current vs. duty cycle (DIP-16)

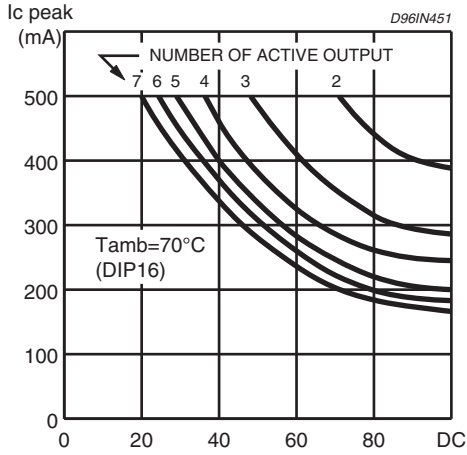
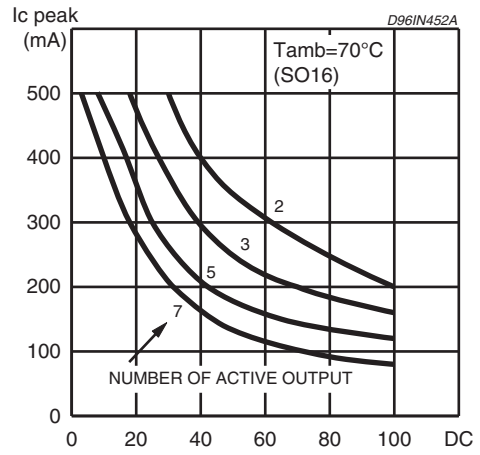


Figure 18. Peak collector current vs. duty cycle (SO-16)



7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

7.1 DIP-16L package information

Figure 19. DIP-16L package outline

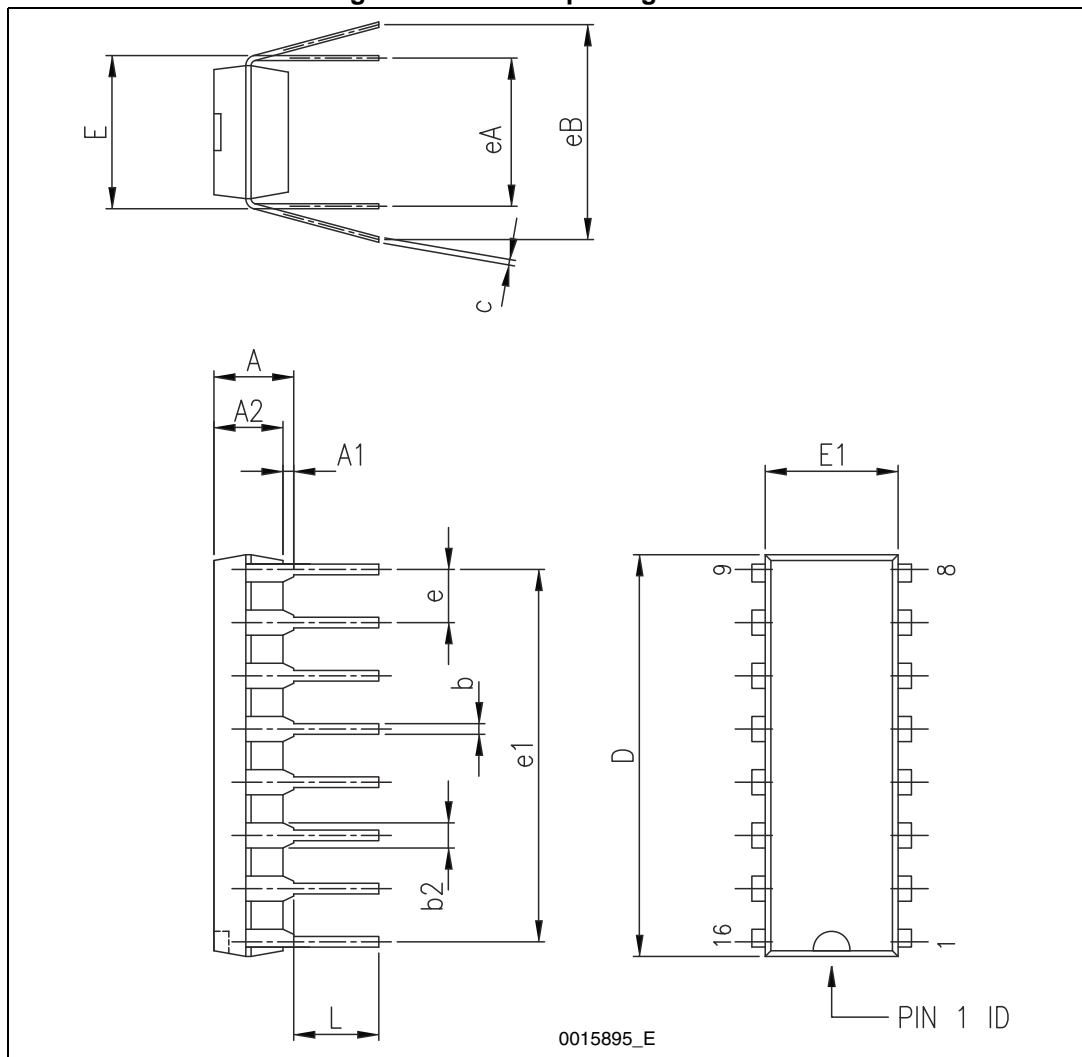


Table 4. DIP-16L mechanical data

Dim.	mm.		
	Min.	Typ.	Max.
A			5.33
A1	0.38		
A2	2.92	3.30	4.95
b	0.36	0.46	0.56
b2	1.14	1.52	1.78
c	0.20	0.25	0.36
D	18067	19.18	19.69
E	7.62	7.87	8.26
E1	6.10	6.35	7.11
e		2.54	
e1		17.78	
eA		7.62	
eB			10.92
L	2.92	3.30	3.81

7.2 SO-16 Narrow package information

Figure 20. SO-16 package outline

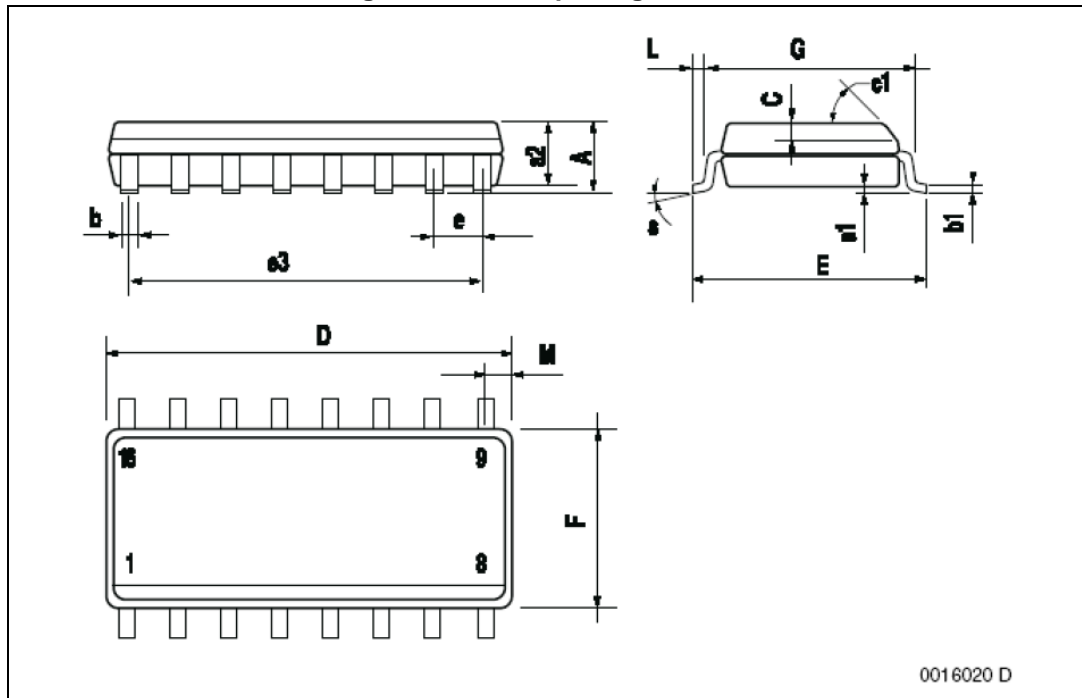


Table 5. SO-16 Narrow mechanical data

Dim.	mm.			inch.		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.25	0.004		0.009
a2			1.6			0.063
b	0.35		0.46	0.014		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.020	
c1			45°	(typ.)		
D(1)	9.8		10	0.386		0.394
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F(1)	3.8		4.0	0.150		0.157
G	4.60		5.30	0.181		0.208
L	0.4		1.27	0.150		0.050
M			0.62			0.024
S	8° (max.)					

8 Order codes

Table 6. Order codes

Part number	Package
ULN2001A	DIP-16
ULN2002A	DIP-16
ULN2003A	DIP-16
ULN2004A	DIP-16
ULN2001D1013TR	SO-16 in tape and reel
ULN2002D1013TR	SO-16 in tape and reel
ULN2003D1013TR	SO-16 in tape and reel
ULN2004D1013TR	SO-16 in tape and reel

9 Revision history

Table 7. Revision history

Date	Revision	Changes
05-Dec-2006	5	Order code updated and document reformatted.
28-Aug-2007	6	Added Table 1 in cover page.
07-May-2012	7	Modified: Figure 12 on page 9. Added: Figure 13, 14, 15 and Figure 16 on page 9.
01-Jun-2012	8	Updated: DIP-16L package mechanical data Table 4 on page 12 and Figure 19 on page 11.
22-Jul-2015	9	Added Plastic DIP16-L package. Removed Device summary table. Updated Table 7: Order code. Added Section 7.2: Plastic DIP-16L package information. Minor text changes.
07-Nov-2017	10	Removed plastic DIP-16L package and associated order code ULN2003A
27-Jun-2018	11	Updated: $I_{I(ON)}$ test condition in Table 3: Electrical characteristics.
09-Jul-2019	12	Added I_F , V_R , ESD parameters in Table 1: Absolute maximum ratings and note in Table 2: Thermal data .

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